



TISP4011H1BJ

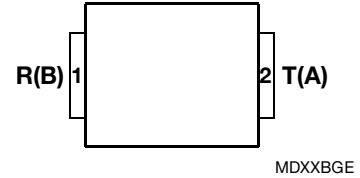
VERY LOW VOLTAGE BIDIRECTIONAL THYRISTOR OVERVOLTAGE PROTECTORS

TISP4011H1BJ VLV Overvoltage Protector Series

General Information

The protector consists of a symmetrical voltage-triggered bidirectional thyristor. Overvoltages are initially clipped by breakdown clamping until the voltage rises to the breakover level, which causes the device to crowbar into a low-voltage on-state condition. This low-voltage on-state causes the current resulting from the overvoltage to be safely diverted through the device. The device switches off when the diverted current falls below the holding current value.

SMB Package (Top View)



Device Symbol



Terminals T and R correspond to the alternative line designators of A and B

Absolute Maximum Ratings, $T_A = 25^\circ\text{C}$ (Unless Otherwise Noted)

Rating	Symbol	Value	Unit
Repetitive peak off-state voltage	V_{DRM}	± 5.25	V
Non-repetitive peak on-state pulse current 10/1000 μs 2/10 μs	I_{PPSM}	± 100 ± 500	A
Junction temperature	T_J	-40 to +150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Electrical Characteristics, $T_A = 25^\circ\text{C}$ (Unless Otherwise Noted)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_D Leakage current	$V_D = V_{\text{DRM}}$		1	200	μA
$V_{\text{(BO)}}$ Breakover voltage	$di/dt = \pm 1 \text{ mA}/\mu\text{s}$		9	10.5	V
$I_{\text{(BO)}}$ Breakover current	$di/dt = \pm 1 \text{ mA}/\mu\text{s}$		75	200	mA
V_T On-state voltage	$I_T = \pm 5 \text{ A}$			3	V
I_H Holding current	$I_T = \pm 5 \text{ A}$, $di/dt = \pm 1 \text{ mA}/\mu\text{s}$	20	60		mA
C_{off} Off-state capacitance	$V_d = 0 \text{ V}$, $f = 1 \text{ MHz}$, 1 V_{rms}		110		pF

*RoHS Directive 2002/95/EC Jan. 27, 2003 including annex and RoHS Recast 2011/65/EU June 8, 2011.

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Specifications are subject to change without notice.

The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time.

Users should verify actual device performance in their specific applications.

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Parameter Measurement Information

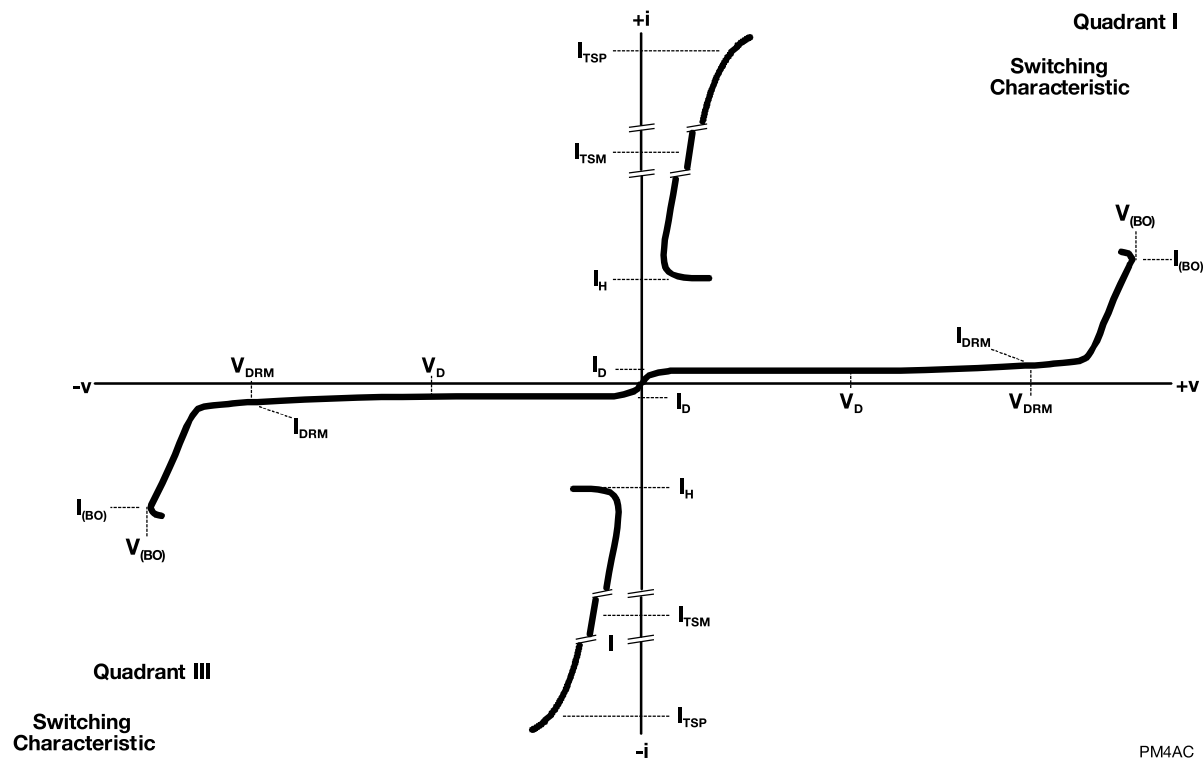


Figure 1. Voltage-Current Characteristic for T and R Terminals
All Measurements are Referenced to the R Terminal

How to Order

Device	Package	Carrier	Order as
TISP4011H1BJ	BJ (SMB/DO-214AA J-Bend)	R (Embossed Tape Reeled)	TISP4011H1BJR-S

Carrier Information

For production quantities, the carrier will be embossed tape reel pack. Evaluation quantities may be shipped in bulk pack or embossed tape.

Package	Carrier	Standard Quantity
SMB	Embossed Tape Reel Pack	3000

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